

80V, 40A, 8.0m Ω max. Silicon N Channel Power MOS FET Power Switching

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting

R07DS0081EJ0300

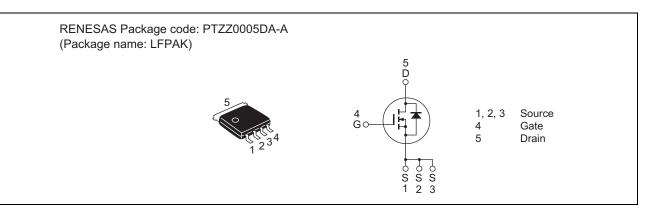
Rev.3.00

Apr 09, 2013

• Low on-resistance

- $R_{DS(on)}\!=6.2~m\Omega$ typ. (at $V_{GS}\!=10~V)$
- Pb-free
- Halogen-free

Outline



Application

• Switching Mode Power Supply

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	80	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	I _D	40	А
Drain peak current	Note1 I _{D(pulse)}	160	А
Body-drain diode reverse drain current	I _{DR}	40	А
Avalanche current	I _{AP} Note 2	20	А
Avalanche energy	E _{AS} Note 2	53.3	mJ
Channel dissipation	Pch Note3	65	W
Channel to Case Thermal Resistance	θch-C	1.92	°C/W
Channel temperature	Tch	150	٥°
Storage temperature	Tstg	-55 to +150	٥C

Notes: 1. $PW \le 10 \ \mu s$, duty cycle $\le 1\%$

2. Value at Tch = 25°C, Rg \geq 50 Ω

3. Tc = 25°C

This product is for the low voltage drive (≤ 10 V).

If the driving voltage is over 10 V under normal conditions, please use the product for high gate to source cutoff voltage $(V_{GS(off)})$ which characteristics has been improved.



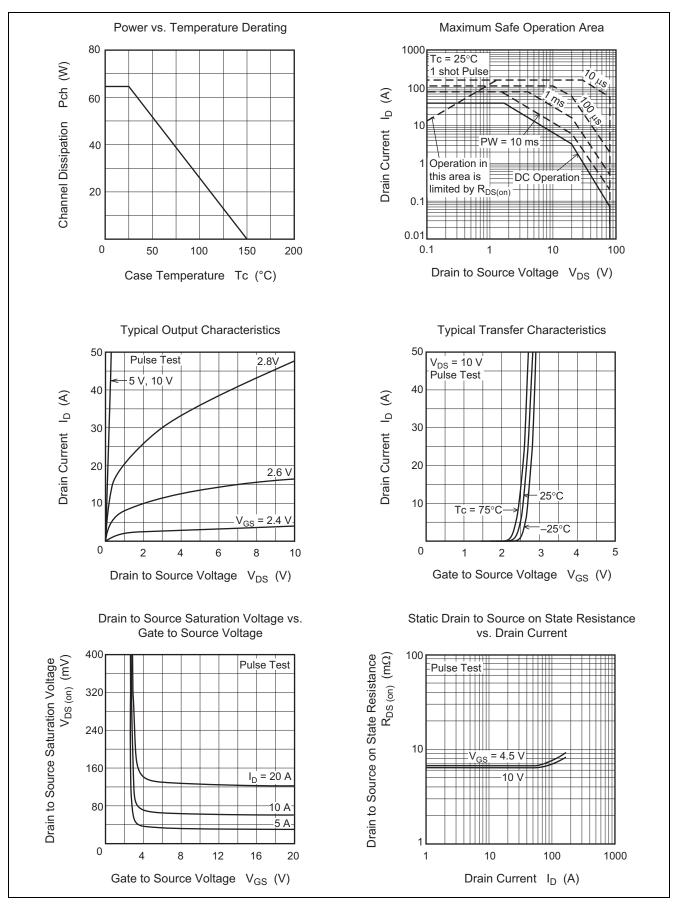
Electrical Characteristics

	-				-	$(Ta = 25^{\circ}C)$
ltem	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR)DSS}	80	—	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$
Gate to source leak current	I _{GSS}	_	—	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}$
Gate to source cutoff voltage	V _{GS(off)}	1.2	_	2.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	6.2	8.0	mΩ	$I_D = 20 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$
resistance	R _{DS(on)}	_	6.7	9.2	mΩ	$I_D = 20 \text{ A}, V_{GS} = 4.5 \text{ V}^{Note4}$
Forward transfer admittance	y _{fs}	_	100	_	S	$I_D = 20 \text{ A}, V_{DS} = 10 \text{ V}^{Note4}$
Input capacitance	Ciss	_	6170	_	pF	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0 \text{ V},$
Output capacitance	Coss		600		pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	235	_	pF	
Gate Resistance	Rg	_	0.5		Ω	
Total gate charge	Qg	_	40		nC	$V_{DD} = 25 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_D = 40 \text{ A}$
Gate to source charge	Qgs	_	19		nC	
Gate to drain charge	Qgd	_	11		nC	
Turn-on delay time	t _{d(on)}	_	14		ns	
Rise time	tr	_	7.2		ns	
Turn-off delay time	t _{d(off)}	_	70		ns	
Fall time	t _f		12		ns	
Body-drain diode forward voltage	V _{DF}		0.82	1.1	V	$I_F = 40 \text{ A}, V_{GS} = 0 \text{ V}^{Note4}$
Body–drain diode reverse recovery	t _{rr}		42		ns	$I_F = 40 \text{ A}, V_{GS} = 0 \text{ V},$ dir/dt = 100 A/us
time						di _F / dt = 100 A/ μs

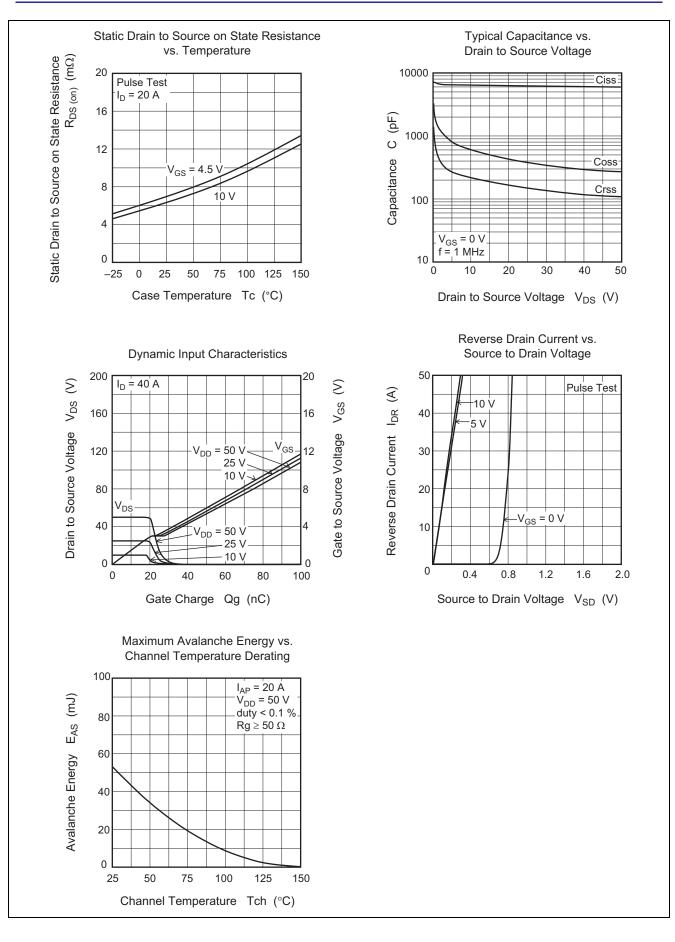
Notes: 4. Pulse test



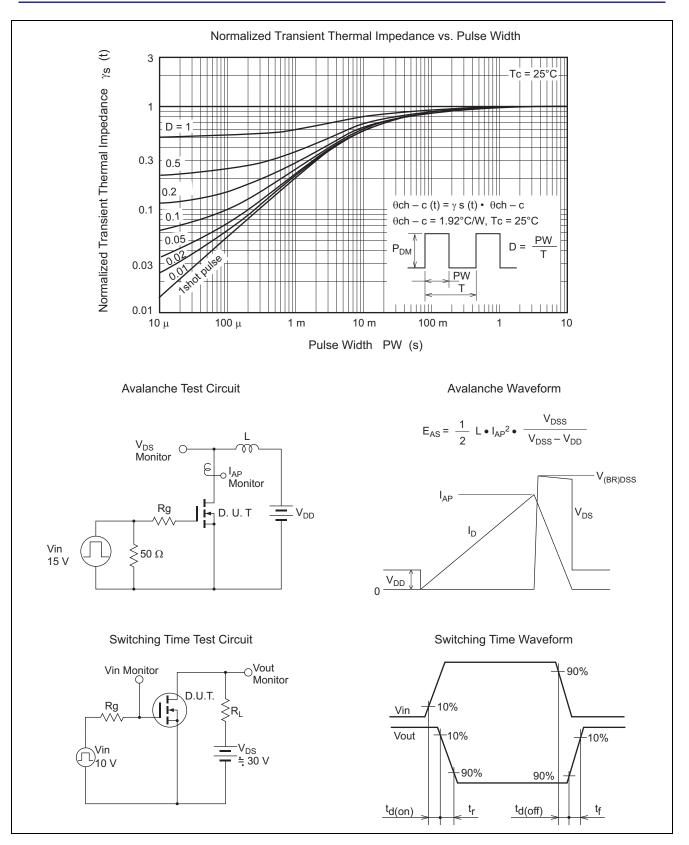
Main Characteristics





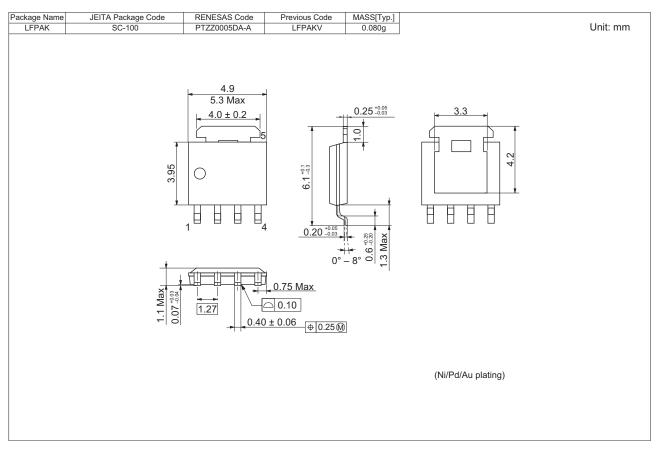








Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
RJK0853DPB-00-J5	2500 pcs	Taping



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Renesas Electronics America Inc.

2880 Scott Boulevard Santa Ciara, CA 95050-2554, U.S.A.

Tel: +1-408-588-6000, Fast: +1-408-588-6130

Renesas Electronics Canada Limited

1011 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada

Tel: +1-905-988-5441, Fast: +1-905-988-3220

Renesas Electronics Europe Limited

Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K

Tel: +44-1628-651-700, Fax: +444-1628-651-804

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Disseldorf, Germany

Tel: +49-211-65030, Fax: +449-211-6503-1327

Renesas Electronics (Shanghal) Co., Ltd.

7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China

Tel: +86-10-8235-1155, Fax: +862-10-8235-7679

Renesas Electronics (Shanghal) Co., Ltd.

Unit 204, 205, AZIA Center, No. 1233 Lujiazui Bing Rd., Pudong District, Shanghai 200120, China

Tel: +862-78587/7588

Renesas Electronics Hong Kong Limited

Unit 1601-1613, 16FL, Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong

Tel: +862-28175-9600, Fax: +862 2886-9022/9044

Renesas Electronics Taiwan Co., Ltd.

137, No, 383, Fu Shing Notth Road, Taipei, Taiwan

Tel: +652-785930, Fax: +852 2886-9022/9044

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